# NSN 5961-01-299-8456

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### Inclosure Material:

Metal

### **Overall Length:**

Between 0.240 inches and 0.260 inches

# Terminal Length:

0.500 inches

### **Overall Diameter:**

Between 0.350 inches and 0.370 inches

### Internal Configuration:

Field effect

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

### To-39

Electrode Internally-electrically Connected To Case:

Drain

### **Mounting Method:**

Terminal

# Terminal Circle Diameter:

0.200 inches

### Features Provided:

Burn in and electrostatic sensitive

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

35.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 15.0 forward gate to source voltage and -0.3 reverse gate to source voltage

### **Current Rating Per Characteristic:**

2.00 amperes drain current and 2.00 milliamperes forward gate current and 100.00 milliamperes reverse gate current with all other

terminals short-circuit to source, junction-gate

# **Power Rating Per Characteristic:**

8.33 watts total device dissipation

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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